

Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC0-RC3 SO55-777CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 848.31 MHz;Duty Cycle: 1:1  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>  
 Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

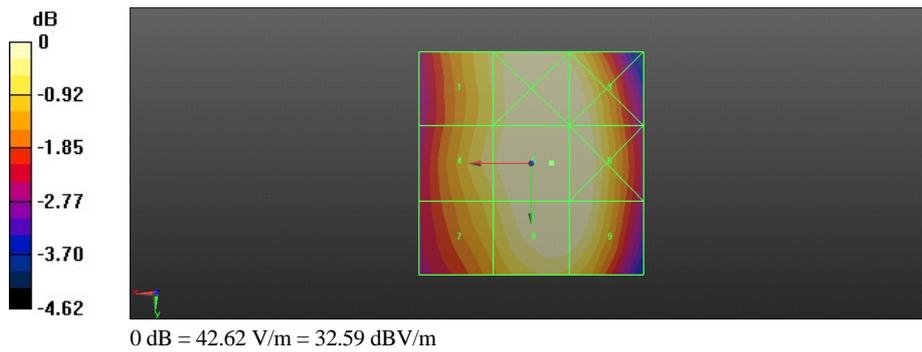
**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm  
 Reference Value = 54.87 V/m; Power Drift = -0.02 dB  
 PMF = 1.050 is applied.  
 E-field emissions = 44.75 V/m  
**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

Grid 1 M4 40.19 V/m	Grid 2 M4 44.13 V/m	Grid 3 M4 43.82 V/m
Grid 4 M4 40.91 V/m	Grid 5 M4 44.75 V/m	Grid 6 M4 44.51 V/m
Grid 7 M4 39.49 V/m	Grid 8 M4 44.14 V/m	Grid 9 M4 43.75 V/m

**Cursor:**  
 Total = 44.75 V/m  
 E Category: M4  
 Location: -4.5, 0, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC0-RC3 SO55-384CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 836.52 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 54.19 V/m; Power Drift = -0.01 dB

PMF = 1.050 is applied.

E-field emissions = 46.21 V/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

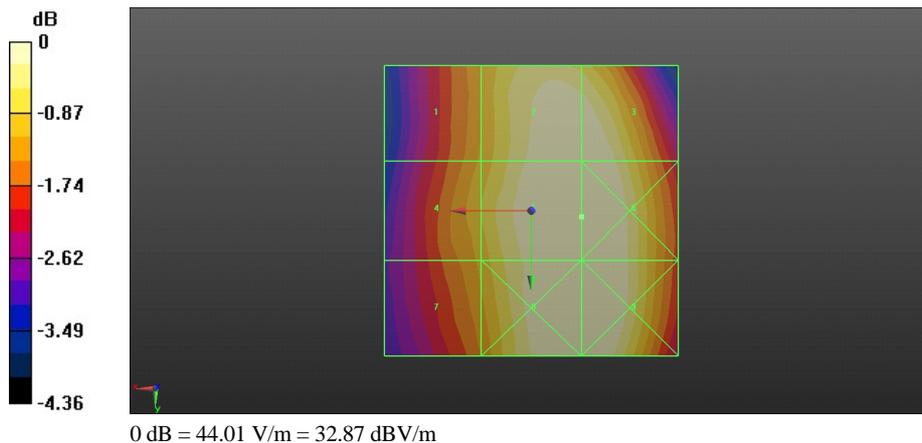
Grid 1 M4 38.86 V/m	Grid 2 M4 44.94 V/m	Grid 3 M4 44.88 V/m
Grid 4 M4 39.89 V/m	Grid 5 M4 46.21 V/m	Grid 6 M4 46.21 V/m
Grid 7 M4 39.00 V/m	Grid 8 M4 46.15 V/m	Grid 9 M4 46.15 V/m

**Cursor:**

Total = 46.21 V/m

E Category: M4

Location: -8.5, 1, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC0-RC3 SO55-1013CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 824.7 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 54.94 V/m; Power Drift = 0.01 dB

PMF = 1.050 is applied.

E-field emissions = 46.88 V/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

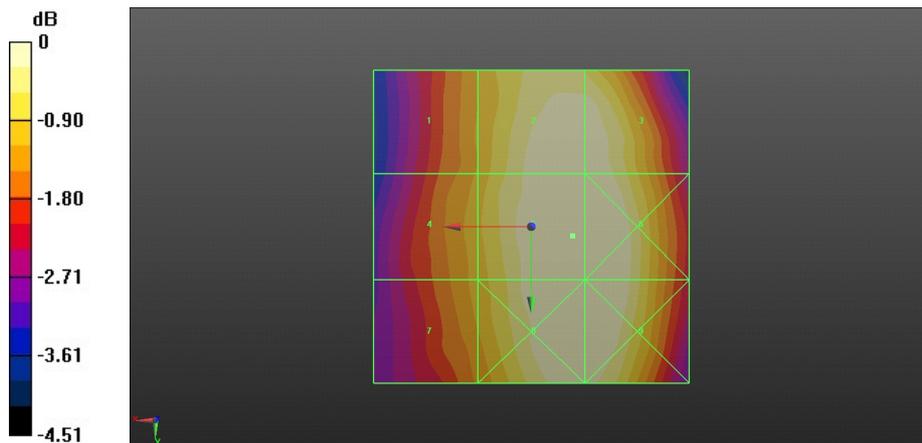
Grid 1 M4 39.13 V/m	Grid 2 M4 45.57 V/m	Grid 3 M4 44.96 V/m
Grid 4 M4 39.97 V/m	Grid 5 M4 46.88 V/m	Grid 6 M4 46.67 V/m
Grid 7 M4 39.54 V/m	Grid 8 M4 46.33 V/m	Grid 9 M4 46.09 V/m

**Cursor:**

Total = 46.88 V/m

E Category: M4

Location: -6.5, 1.5, 8.7 mm



0 dB = 44.65 V/m = 33.00 dBV/m

Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC1-RC3 SO55-1175CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1908.75 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.64 V/m; Power Drift = -0.04 dB

PMF = 1.020 is applied.

E-field emissions = 32.38 V/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

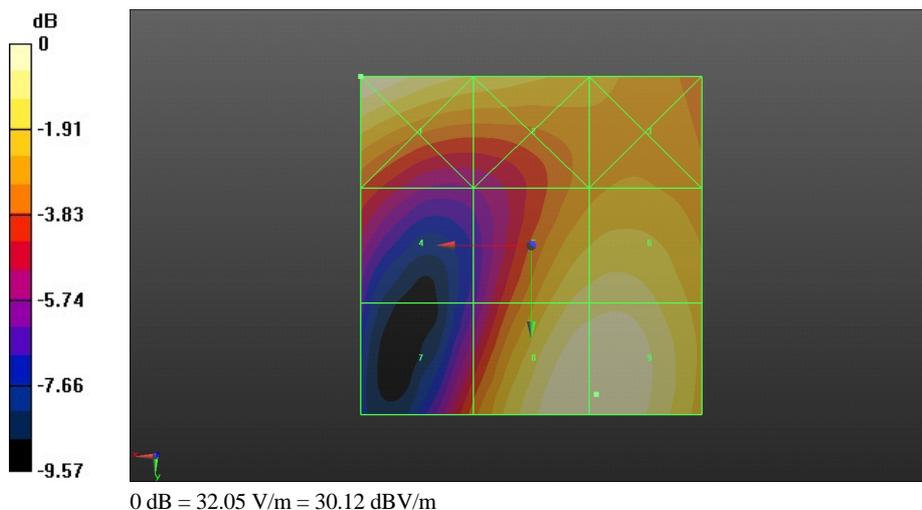
<b>Grid 1 M4</b> <b>32.69 V/m</b>	<b>Grid 2 M4</b> <b>27.37 V/m</b>	<b>Grid 3 M4</b> <b>24.81 V/m</b>
<b>Grid 4 M4</b> <b>20.81 V/m</b>	<b>Grid 5 M4</b> <b>28.79 V/m</b>	<b>Grid 6 M4</b> <b>29.34 V/m</b>
<b>Grid 7 M4</b> <b>21.56 V/m</b>	<b>Grid 8 M4</b> <b>32.33 V/m</b>	<b>Grid 9 M4</b> <b>32.38 V/m</b>

**Cursor:**

Total = 32.69 V/m

E Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC1-RC3 SO55-600CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 23.14 V/m; Power Drift = -0.19 dB

PMF = 1.020 is applied.

E-field emissions = 31.59 V/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

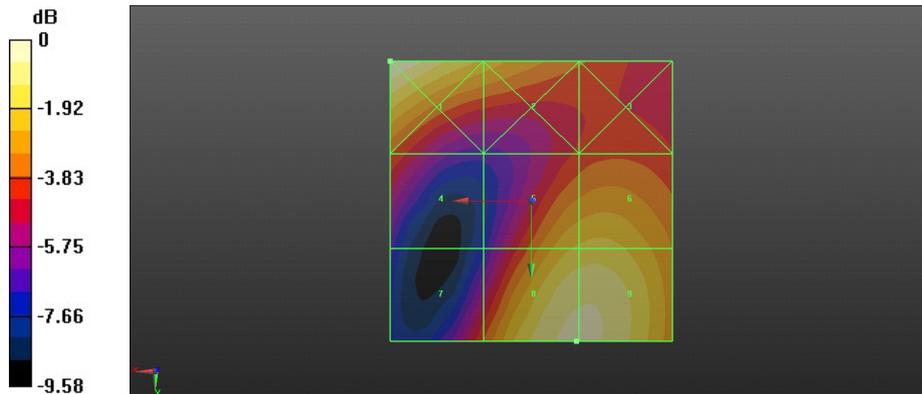
Grid 1 M4 34.07 V/m	Grid 2 M4 26.33 V/m	Grid 3 M4 21.79 V/m
Grid 4 M4 21.79 V/m	Grid 5 M4 27.26 V/m	Grid 6 M4 27.71 V/m
Grid 7 M4 21.59 V/m	Grid 8 M4 31.59 V/m	Grid 9 M4 31.59 V/m

**Cursor:**

Total = 34.07 V/m

E Category: M4

Location: 25, -25, 8.7 mm



0 dB = 33.40 V/m = 30.47 dBV/m

Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_ER3DV6\_H881C-CDMA BC1-RC3 SO55-25CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1851.25 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2480; ConvF(1, 1, 1); Calibrated: 2012-1-4;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device E-Field measurement (E-field scan for ANSI C63.19-2007 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1); Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 21.95 V/m; Power Drift = 0.09 dB

PMF = 1.020 is applied.

E-field emissions = 31.21 V/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled E-field

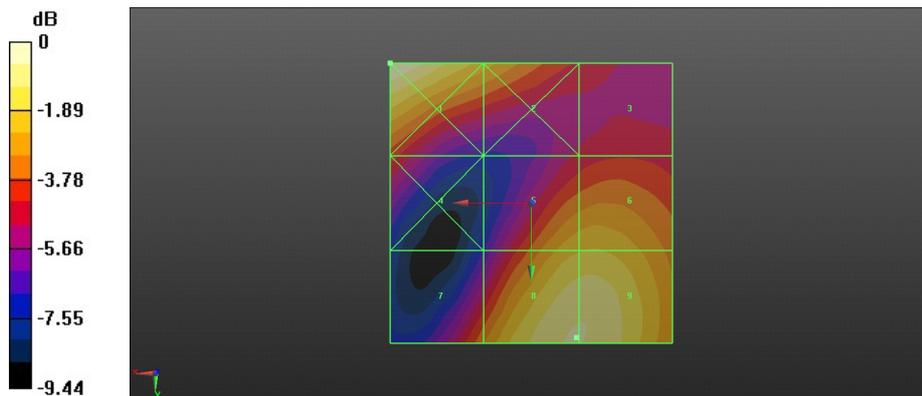
<b>Grid 1 M4</b> <b>34.11 V/m</b>	<b>Grid 2 M4</b> <b>26.03 V/m</b>	<b>Grid 3 M4</b> <b>20.06 V/m</b>
<b>Grid 4 M4</b> <b>21.03 V/m</b>	<b>Grid 5 M4</b> <b>26.79 V/m</b>	<b>Grid 6 M4</b> <b>27.12 V/m</b>
<b>Grid 7 M4</b> <b>23.15 V/m</b>	<b>Grid 8 M4</b> <b>31.21 V/m</b>	<b>Grid 9 M4</b> <b>31.20 V/m</b>

**Cursor:**

Total = 34.11 V/m

E Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC0-RC3 SO55-777CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 848.31 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.07700 A/m; Power Drift = -0.04 dB

PMF = 0.9900 is applied.

H-field emissions = 0.09636 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

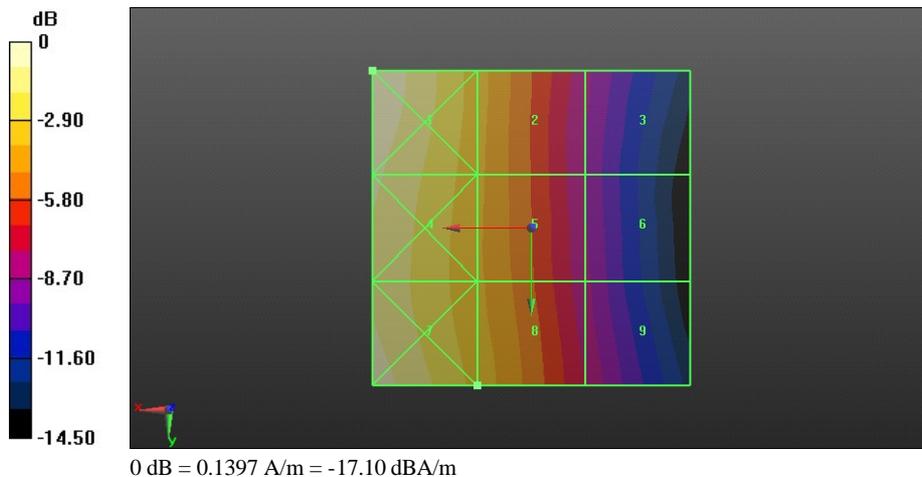
<b>Grid 1 M4</b> <b>0.138 A/m</b>	<b>Grid 2 M4</b> <b>0.094 A/m</b>	<b>Grid 3 M4</b> <b>0.053 A/m</b>
<b>Grid 4 M4</b> <b>0.128 A/m</b>	<b>Grid 5 M4</b> <b>0.092 A/m</b>	<b>Grid 6 M4</b> <b>0.053 A/m</b>
<b>Grid 7 M4</b> <b>0.134 A/m</b>	<b>Grid 8 M4</b> <b>0.096 A/m</b>	<b>Grid 9 M4</b> <b>0.057 A/m</b>

**Cursor:**

Total = 0.1383 A/m

H Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC0-RC3 SO55-384CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 836.52 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.07400 A/m; Power Drift = -0.02 dB

PMF = 0.9900 is applied.

H-field emissions = 0.09111 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

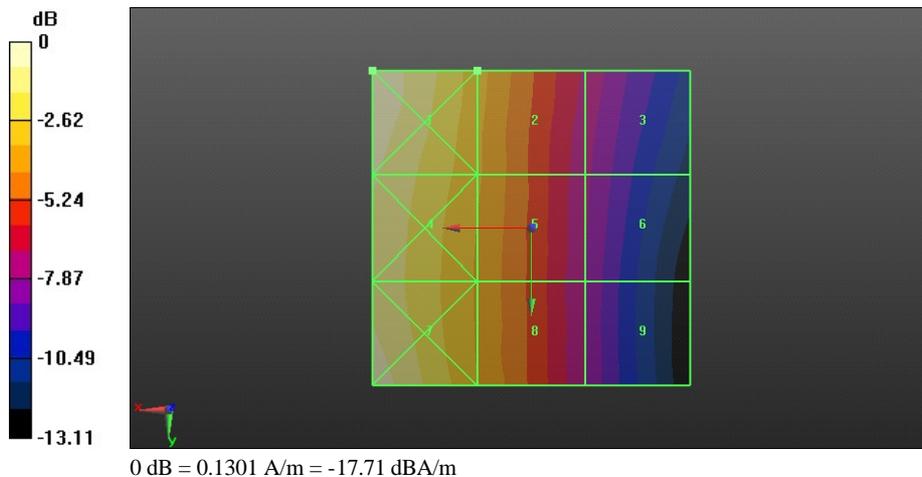
<b>Grid 1 M4</b> <b>0.129 A/m</b>	<b>Grid 2 M4</b> <b>0.091 A/m</b>	<b>Grid 3 M4</b> <b>0.057 A/m</b>
<b>Grid 4 M4</b> <b>0.120 A/m</b>	<b>Grid 5 M4</b> <b>0.089 A/m</b>	<b>Grid 6 M4</b> <b>0.054 A/m</b>
<b>Grid 7 M4</b> <b>0.126 A/m</b>	<b>Grid 8 M4</b> <b>0.088 A/m</b>	<b>Grid 9 M4</b> <b>0.053 A/m</b>

**Cursor:**

Total = 0.1288 A/m

H Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC0-RC3 SO55-1013CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 824.7 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.07700 A/m; Power Drift = 0.02 dB

PMF = 0.9900 is applied.

H-field emissions = 0.09195 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

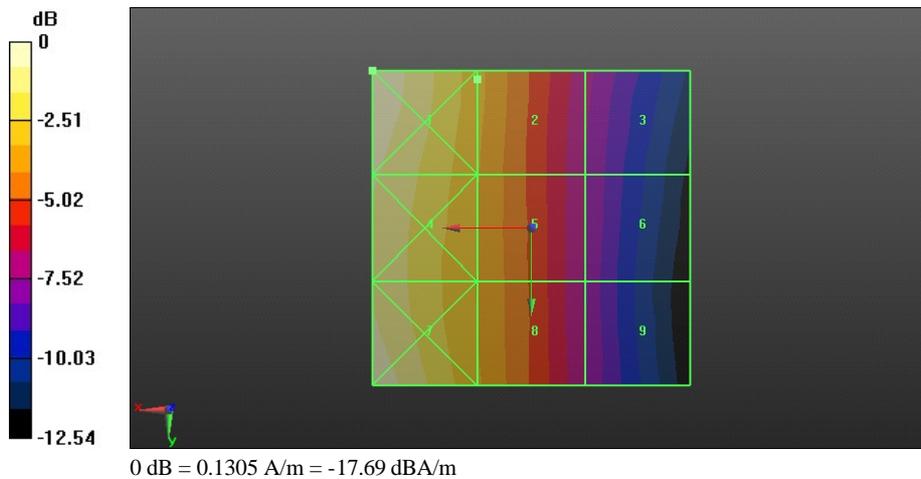
<b>Grid 1 M4</b> <b>0.129 A/m</b>	<b>Grid 2 M4</b> <b>0.092 A/m</b>	<b>Grid 3 M4</b> <b>0.057 A/m</b>
<b>Grid 4 M4</b> <b>0.120 A/m</b>	<b>Grid 5 M4</b> <b>0.090 A/m</b>	<b>Grid 6 M4</b> <b>0.055 A/m</b>
<b>Grid 7 M4</b> <b>0.128 A/m</b>	<b>Grid 8 M4</b> <b>0.090 A/m</b>	<b>Grid 9 M4</b> <b>0.055 A/m</b>

**Cursor:**

Total = 0.1292 A/m

H Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC1-RC3 SO55-1175CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1908.75 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.09400 A/m; Power Drift = -0.04 dB

PMF = 0.9400 is applied.

H-field emissions = 0.08522 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

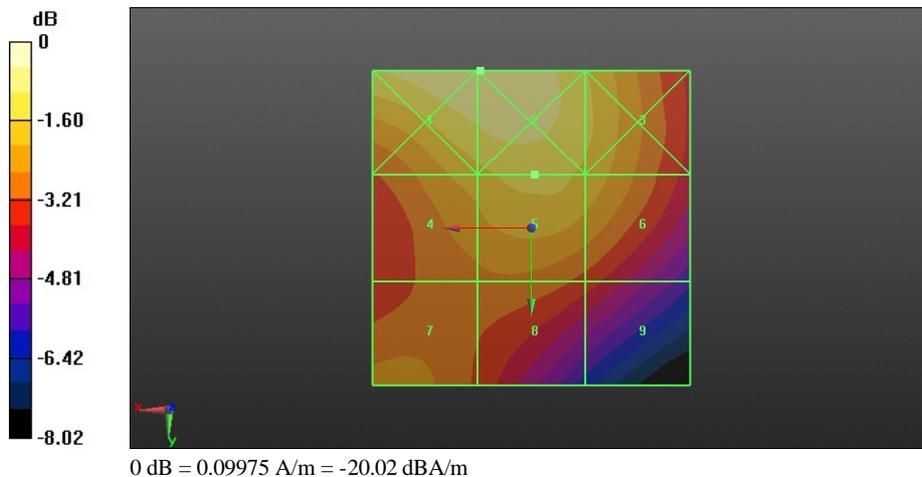
Grid 1 M4 <b>0.094 A/m</b>	Grid 2 M4 <b>0.094 A/m</b>	Grid 3 M4 <b>0.084 A/m</b>
Grid 4 M4 <b>0.081 A/m</b>	Grid 5 M4 <b>0.085 A/m</b>	Grid 6 M4 <b>0.082 A/m</b>
Grid 7 M4 <b>0.076 A/m</b>	Grid 8 M4 <b>0.073 A/m</b>	Grid 9 M4 <b>0.067 A/m</b>

**Cursor:**

Total = 0.09376 A/m

H Category: M4

Location: 8, -25, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC1-RC3 SO55-600CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1880 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.09300 A/m; Power Drift = -0.04 dB

PMF = 0.9400 is applied.

H-field emissions = 0.08146 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

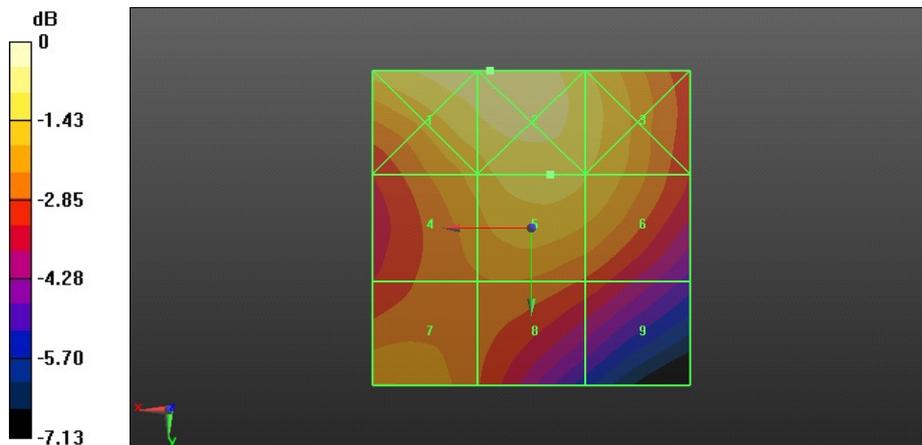
Grid 1 M4 <b>0.088 A/m</b>	Grid 2 M4 <b>0.088 A/m</b>	Grid 3 M4 <b>0.082 A/m</b>
Grid 4 M4 <b>0.077 A/m</b>	Grid 5 M4 <b>0.081 A/m</b>	Grid 6 M4 <b>0.080 A/m</b>
Grid 7 M4 <b>0.075 A/m</b>	Grid 8 M4 <b>0.071 A/m</b>	Grid 9 M4 <b>0.067 A/m</b>

**Cursor:**

Total = 0.08783 A/m

H Category: M4

Location: 6.5, -25, 8.7 mm



0 dB = 0.09344 A/m = -20.59 dBA/m

Test Laboratory: HUAWEI SAR/HAC Lab

**HAC\_H3DV6\_H881C-CDMA BC1-RC3 SO55-25CH**

**DUT: H881C; Type: CDMA 2000 Digital Mobile Phone;Horizon; Serial: SAR1**

Communication System: HW-CDMA 2000; Frequency: 1851.25 MHz;Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY Configuration:

- Probe: H3DV6 - SN6305; ; Calibrated: 2012-1-4
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn913; Calibrated: 2011-12-23
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.3(988); SEMCAD X 14.6.7(6848)

**Device H-Field measurement with H3DV6 probe (H-field scan for ANSI C63.19-2007 compliance)/H Scan - H3DV6: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm**

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.09100 A/m; Power Drift = -0.03 dB

PMF = 0.9400 is applied.

H-field emissions = 0.07933 A/m

**Near-field category: M4 (AWF 0 dB)**

PMF scaled H-field

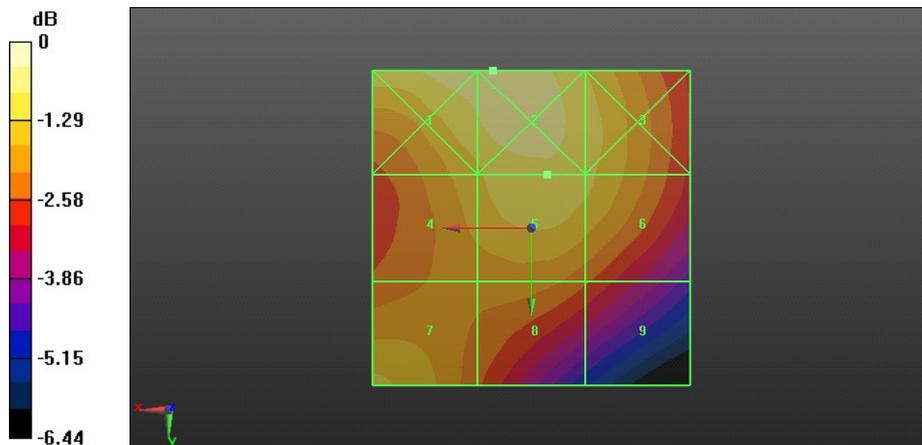
<b>Grid 1 M4</b> <b>0.083 A/m</b>	<b>Grid 2 M4</b> <b>0.083 A/m</b>	<b>Grid 3 M4</b> <b>0.078 A/m</b>
<b>Grid 4 M4</b> <b>0.075 A/m</b>	<b>Grid 5 M4</b> <b>0.079 A/m</b>	<b>Grid 6 M4</b> <b>0.077 A/m</b>
<b>Grid 7 M4</b> <b>0.078 A/m</b>	<b>Grid 8 M4</b> <b>0.071 A/m</b>	<b>Grid 9 M4</b> <b>0.066 A/m</b>

**Cursor:**

Total = 0.08300 A/m

H Category: M4

Location: 6, -25, 8.7 mm



0 dB = 0.08830 A/m = -21.08 dBA/m